CAT93LC56/CAT93LC56I

2K-Bit SERIAL E2PROM

FEATURES

- **Low Power CMOS Technology**
- **Single 3V Supply**
- 128 x 16 or 256 x 8 Selectable Serial Memory
- Self-Timed Write Cycle with Auto-Clear
- Hardware and Software Write Protection
- Power-Up Inadvertant Write Protection
- 100,000 Program/Erase Cycles
- 100 Year Data Retention
- Optional High Endurance Device Available

3

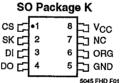
DESCRIPTION

The CAT93LC56 and CAT93LC56I are 2K bit Serial E^2 PROM memory devices which can be configured as either 128 registers by 16 bits (ORG pin at V_{CC}) or 256 registers by 8 bits (ORG pin at GND). Each register can be written (or read) serially by using the DI (or DO) pin. The CAT93LC56/CAT93LC56I is manufactured using

Catalyst's advanced CMOS E²PROM floating gate technology. It is designed to endure 100,000 program/erase cycles and has a data retention of 100 years. The device is available in 8 pin DIP or SO packages.

PIN CONFIGURATION

DIP Packa	age	SO Pa	ckage S
CS -1 8 SK 2 7 DI 3 6	□ V _{CC} □ NC □ ORG	CS [•1 SK [2 DI [3	8 12 VCC 7 12 NC 6 12 ORG 5 13 GND

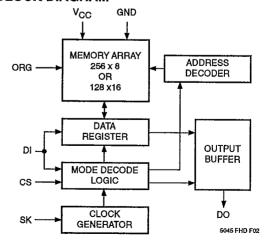


PIN FUNCTIONS

Pin Name	Function					
cs	Chip Select					
SK	Clock Input					
DI	Serial Data Input					
DO	Serial Data Output					
Vcc	+3V Power Supply					
GND	Ground					
NC	No Connection					
ORG	Memory Organization					

Note: When the ORG pin is connected to $V_{\rm CC}$, the 128 x 16 organization is selected. When it is connected to ground, the 256 x 8 organization is selected. If the ORG pin is left unconnected, then an internal pullup device will select the 128 x 16 organization.

BLOCK DIAGRAM



TD 5045

ABSOLUTE MAXIMUM RATINGS*

Temperature Under Bias55°C to +125°C
Storage Temperature65°C to +150°C
Voltage on any Pin with Respect to Ground ⁽¹⁾ 2.0V to +V _{CC} +2.0V
V _{CC} with Respect to Ground2.0V to +7.0V
Package Power Dissipation Capability (Ta = 25°C)1.0W
Lead Soldering Temperature (10 secs)300°C
Output Short Circuit Current ⁽²⁾ 100 m/

*COMMENT

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions outside of those listed in the operational sections of this specification is not implied. Exposure to any absolute maximum rating for extended periods may affect device performance and reliability.

RELIABILITY CHARACTERISTICS

Symbol	Parameter	Min.	Max.	Units	Reference Test Method
N _{END} (3)	Endurance	100,000		Cycles/Byte	MIL-STD-883, Test Method 1033
T _{DR} (3)	Data Retention	100		Years	MIL-STD-883, Test Method 1008
V _{ZAP} (3)	ESD Susceptibility	2000		Volts	MIL-STD-883, Test Method 3015
I _{LTH} (3)(4)	Latch-Up	100		mA	JEDEC Standard 17

D.C. OPERATING CHARACTERISTICS

CAT93LC56 T_A= 0°C to +70°C, V_{CC} = +3V±10%, unless otherwise specified. CAT93LC56I T_A = -40°C to +85°C, V_{CC} = +3V±10%, unless otherwise specified.

			Limits			
Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
lcc1	Power Supply Current (Operating)			2	mA	DI = 0.0V, SK = 3.0V V _{CC} = 3.0V, CS = 3.0V, Output Open
Icc2	Power Supply Current (Standby)			50	μА	V _{CC} = 3.3V, CS = 0V DI = 0V SK = 0V
ILI	Input Leakage Current			2	μА	V _{IN} = 0V to 3.3V
lo	Output Leakage Current (Including ORG Pin)	,		10	μА	V _{OUT} = 0V to 3.3V, CS = 0V
V _{IH}	High Level Input Voltage	V _{CC} - 0.3		V _{CC} + 1	٧	
V _{IL}	Low Level Input Voltage	-0.1		0.3	V	
VoH	High Level Output Voltage	V _{CC} - 0.3			V	I _{OH} = -10μA
Vol	Low Level Output Voltage			0.3	V	loL = 10μA

Note:

(2) Output shorted for no more than one second. No more than one output shorted at a time.

(3) This parameter is tested initially and after a design or process change that affects the parameter.

⁽¹⁾ The minimum DC input voltage is -0.5V. During transitions, inputs may undershoot to -2.0V for periods of less than 20 ns. Maximum DC voltage on output pins is V_{CC} +0.5V, which may overshoot to V_{CC} +2.0V for periods of less than 20 ns.

⁽⁴⁾ Latch-up protection is provided for stresses up to 100 mA on address and data pins from -1V to V_{CC} +1V.

INSTRUCTION SET

			Address		Data		
Instruction	Start Bit	Opcode	256 x 8	128 x 16	256 x 8	128 x 16	Comments
READ(5)	1	1 0	A8A0	A7-A0			Read Address AN-A0
ERASE(5)	1	1 1	A8-A0	A7-A0			Clear Address AN-A0
WRITE(5)	1	0 1	A8-A0	A7-A0	D7-D0	D15-D0	Write Address AN-A0
EWEN	1	0.0	11XXXXXXX	11XXXXXX			Write Enable
EWDS	1	0.0	00XXXXXXX	00XXXXXX			Write Disable
ERAL	1	0.0	10XXXXXXX	10XXXXXX			Clear All Addresses
WRAL ⁽⁶⁾	1	0.0	01XXXXXXX	01XXXXXX	D7D0	D15-D0	Write All Addresses

A.C. CHARACTERISTICS

CAT93LC56 T_A= 0°C to +70°C, V_{CC} = +3V±10%, unless otherwise specified. CAT93LC56I T_A= -40°C to +85°C, V_{CC} = +3V±10%, unless otherwise specified.

			Limits			
Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
tcss	CS Setup Time	200			ns	
tcsH	CS Hold Time	0			ns	C _L = 100pF
t _{DIS}	DI Setup Time	400			ns	$V_{OL} = 0.3V$
t _{DIH}	DI Hold Time	400			ns	$V_{OH} = V_{CC} - 0.3$
t _{PD1}	Output Delay to 1			2	μs	$V_{IL} = 0.3V$
t _{PD0}	Output Delay to 0			2	μs	$V_{IH} = V_{CC} - 0.3$
t _{HZ} (3)	Output Delay to High-Z			400	ns	
tew	Program/Erase Pulse Width			20	ms	
tcsmin	Minimum CS Low Time	1		4P.4	μs	
tskHI	Minimum SK High Time	1			μs	
tsklow	Minimum SK Low time	1		7+7	με	
tsv	Output Delay to Status Valid			1	μs	C _L = 100pF
SK _{MAX}	Maximum Clock Frequency	DC		250	kHz	

⁽³⁾ This parameter is tested initially and after a design or process change that affects the parameter.
(5) Address bit A8 for 256 x 8 ORG and A7 for 128 x 16 ORG are "Don't Care" bits, but must be kept at either a "1" or "0" for READ, WRITE and ERASE commands.

⁽⁶⁾ The WRAL command is for test mode only and is not guaranteed over operating conditions.

DEVICE OPERATION

The CAT93LC56/CAT93LC56l is a 2048 bit nonvolatile memory intended for use with industry standard microprocessors. The CAT93LC56/CAT93LC56l can be organized as either 128 registers by 16 bits, or as 256 registers by 8 bits. Seven 11 bit instructions (12 bit instruction in 256 by 8 organization) control the reading, writing and erase operations of the device. The CAT93LC56/CAT93LC56l operates on a single 3V supply and will generate on chip, the high voltage required during any write operation.

Instructions, addresses, and write data are clocked into the DI pin on the rising edge of the clock (SK). The DO pin is normally in a high impedance state except when reading data from the device, or when checking the ready/busy status after a write operation.

The ready/busy status can be determined after a write

operation by selecting the device (CS high) and polling the DO pin; DO low indicates that the write operation is not completed, while DO high indicates that the device is ready for the next instruction. If necessary, the DO pin may be placed back into a high impedance state during chip select by shifting a dummy "1" into the DI pin. The DO pin will enter the high impedance state on the falling edge of the clock (SK). Placing the DO pin into the high impedance state is recommended in applications where the DI pin and the DO pin are to be tied together to form a common DI/O pin.

The format for all instructions sent to the CAT93LC56/CAT93LC56l is a logical "1" start bit, a 2 bit (or 4 bit) op code, a 8 bit address (9 bit address when organized as 256×8), and for write operations a 16 bit data field (8 bit data field when organized as 256×8).

Figure 1. Sychronous Data Timing (7)

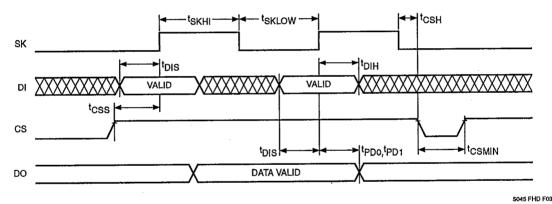
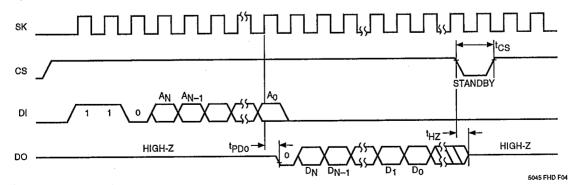


Figure 2. Read Instruction Timing (7)



(7) The ORG pin is used to configure the device for x8 or x16 operation. When x8 organization is selected, AN = A8 and DN = D7. When x16 organization is selected, AN = A7 and DN = D15.

At power-down, when Vcc falls below a threshold of approximately 2.4V, the data protection circuitry inhibits the erase and write instructions and a write disable (EWDS) is executed internally.

Read

Upon receiving a READ command and an address (clocked into the DI pin), the DO pin of the CAT93LC56/CAT93LC56I will come out of the high impedance state and, after sending an initial dummy zero bit, will begin shifting out the data addressed. The output data bits will toggle on the rising edge of the SK clock and are stable after the specified time delay (tpdo or tpd1). The most significant bit of the address is a "Don't Care" bit, but it must be kept at either a "1" or a "0" for READ, WRITE and ERASE commands.

Write

After receiving a WRITE command, address and the

data, the CS (chip select) pin must be deselected for a minimum of 1µs (tcsmin). The falling edge of CS will start the self clocking clear and data store cycle of the memory location specified in the instruction. The clocking of the SK pin is not necessary after the device has entered the self clocking mode. The ready/busy status of the CAT93LC56/CAT93LC56I can be determined by selecting the device and polling the DO pin. Since this device features Auto-Clear before write, it is NOT necessary to erase a memory location before the WRITE command is sent. The most significant bit of the address is a "Don't Care" bit, but it must be kept at either a "1" or a "0" for READ, WRITE and ERASE commands.

Erase

Upon receiving an ERASE command and address, the CS (chip select) pin must be deselected for a minimum of 1µs (tcsmin). The falling edge of CS will start the self clocking clear cycle of the memory location specified in the instruction. The clocking of the SK pin is not neces-



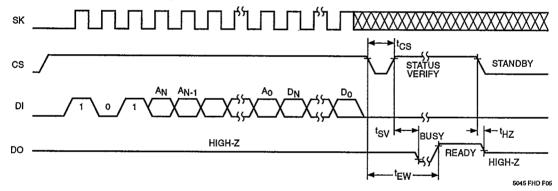
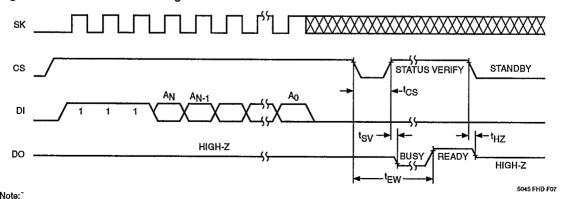


Figure 4. Erase Instruction Timing (7)



(7) The ORG pin is used to configure the device for x8 or x16 operation. When x8 organization is selected, AN = A8 and DN = D7. When x16 organization is selected, AN = A7 and DN = D15.

sary after the device has entered the self clocking mode. The ready/busy status of the CAT93LC56/CAT93LC56l can be determined by selecting the device and polling the DO pin. Once cleared, the content of a cleared location returns to a logical "1" state. The most significant bit of the address is a "Don't Care" bit, but it must be kept at either a "1" or a "0" for READ, WRITE and ERASE commands.

Erase/Write Enable and Disable

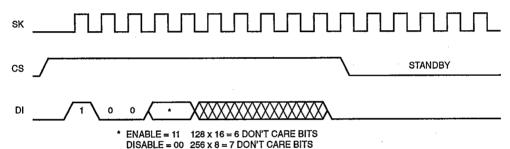
The CAT93LC56/CAT93LC56I powers up in the write disable state. Any writing after power-up or after an EWDS (write disable) instruction must first be preceded by the EWEN (write enable) instruction. Once the write instruction is enabled, it will remain enabled until power to the device is removed, or the EWDS instruction is

sent. The EWDS instruction can be used to disable all CAT93LC56/CAT93LC56I write and clear instructions, and will prevent any accidental writing or clearing of the device. Data can be read normally from the device regardless of the write enable/disable status.

Erase All

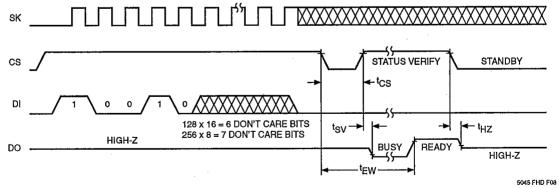
Upon receiving an ERAL command, the CS (chip select) pin must be deselected for a minimum of 1µs (tcsmin). The falling edge of CS will start the self clocking clear cycle of all memory locations in the device. The clocking of the SK pin is not necessary after the device has entered the self clocking mode. The ready/busy status of the CAT93LC56/CAT93LC56i can be determined by selecting the device and polling the DO pin. Once cleared, the contents of all memory bits return to a logical "1" state.

Figure 5. EWEN/EWDS Instruction Timing (7)



5045 FHD F06

Figure 6. ERAL Instruction Timing (7)



Note:

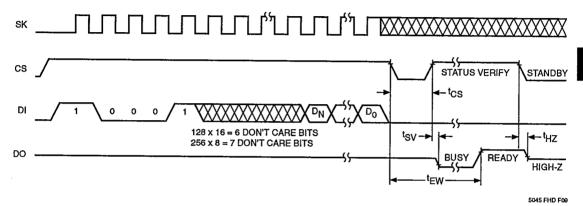
(7) The ORG pin is used to configure the device for x8 or x16 operation. When x8 organization is selected, AN = A8 and DN = D7. When x16 organization is selected, AN = A7 and DN = D15.

Write All

Upon receiving a WRAL command and data, the CS (chip select) pin must be deselected for a minimum of 1µs (tcsmin). The falling edge of CS will start the self clocking data write to all memory locations in the device. The clocking of the SK pin is not necessary after the

device has entered the self clocking mode. The ready/ busy status of the CAT93LC56/CAT93LC56I can be determined by selecting the device and polling the DO pin. It IS NOT necessary for all memory locations to be cleared before the WRAL command is executed.

Figure 7. WRAL Instruction Timing (7)



Note:

⁽⁷⁾ The ORG pin is used to configure the device for x8 or x16 operation. When x8 organization is selected, AN = A8 and DN = D7. When x16 organization is selected, AN = A7 and DN = D15.